

Mikhail N Lapushkin

List of Publications by Year in descending order

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#	ARTICLE	IF	CITATIONS
1	Formation of diethylamine thermal ionization mass spectrum on NaAu _x intermetallide. <i>Rapid Communications in Mass Spectrometry</i> , 2021, 35, e9144.	1.5	4
2	Thermal ionization of tetramethyltetrazene molecules on NaAu _y surface. <i>European Journal of Mass Spectrometry</i> , 2020, 26, 351-360.	1.0	4
3	Electronic Structure of Molybdenum Oxidized in Air. <i>Physics of the Solid State</i> , 2019, 61, 1993-1998.	0.6	1
4	The Electronic Structure of the Cs/n-GaN(0001) Nano-Interface. <i>Technical Physics Letters</i> , 2018, 44, 247-250.	0.7	5
5	Synchrotron-based photoemission study of electronic structure of the Cs/GaN ultrathin interface. <i>Solid State Communications</i> , 2018, 271, 6-10.	1.9	3
6	The Influence of Charge Transfer on Ion Emission from NaAu _y Film. <i>Technical Physics Letters</i> , 2018, 44, 713-715.	0.7	0
7	Soft x-ray photoemission spectroscopy of the Ba atomic layer deposition on the ceramic multiferroic BiFeO ₃ . <i>Applied Surface Science</i> , 2017, 400, 172-175.	6.1	5
8	Photoemission of the K/W(100) system in the O ₂ atmosphere. <i>Technical Physics</i> , 2017, 62, 1104-1111.	0.7	0
9	Photoemission studies of the vicinal SiC(100) 4° surface and the Cs/SiC(100) 4° interface. <i>Technical Physics Letters</i> , 2016, 42, 1145-1148.	0.7	3
10	Synchrotron radiation photoemission study of the ultrathin Cs/InN interface. <i>Solid State Communications</i> , 2015, 217, 34-37.	1.9	4
11	Transport of ions and charged droplets from the atmospheric region into a gas dynamic interface. <i>Journal of Analytical Chemistry</i> , 2013, 68, 1151-1157.	0.9	7
12	Surface states and accumulation nanolayer induced by Ba and Cs adsorption on the n-GaN(0001) surface. <i>Surface Science</i> , 2009, 603, 2474-2478.	1.9	21
13	Charge accumulation in ultrathin Cs / n - GaN and Cs / n - InGaN interfaces. <i>Solid State Communications</i> , 2007, 143, 476-480.	1.9	9
14	Initial stages in the formation of a CsAu surface alloy. <i>Technical Physics Letters</i> , 1998, 24, 390-392.	0.7	11
15	Near-Fermi level surface states induced by Cs adsorption on the Si(111)7 × 7 surface. <i>Surface Science</i> , 1995, 331-333, 552-556.	1.9	12
16	Near-threshold enhancement in photoemission from alkali metal overlayers. <i>Surface Science</i> , 1994, 302, 303-313.	1.9	39
17	Electronic surface states of submonolayer Cs and Ba films on (100), (110), (111) W. <i>Physics Letters, Section A: General, Atomic and Solid State Physics</i> , 1989, 137, 139-143.	2.1	5